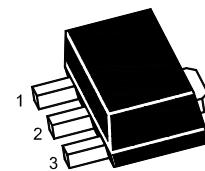


HSC2881U**NPN Silicon Epitaxial Planar Transistor**

Power amplifier

1.Base 2.Collector 3.Emitter
SOT-89 Plastic Package**Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)**

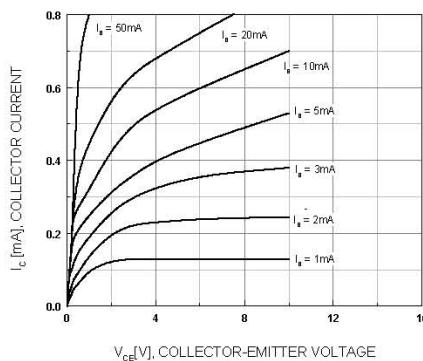
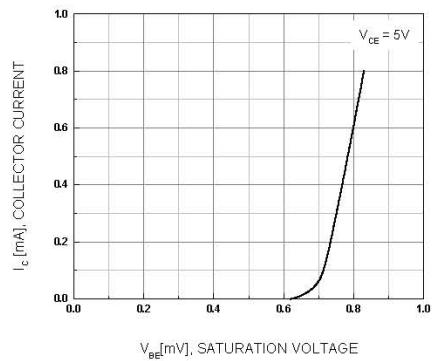
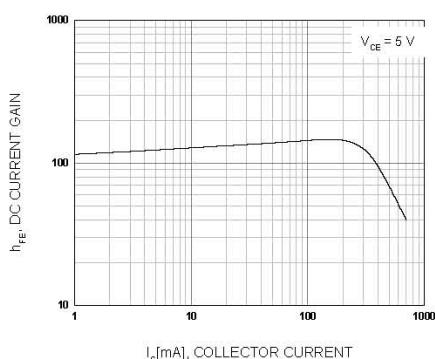
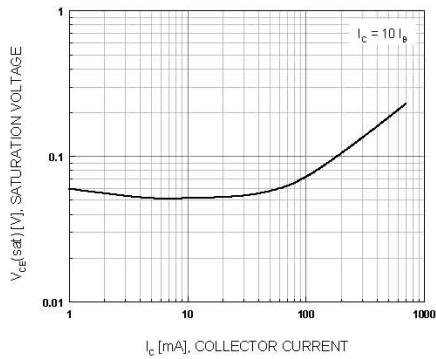
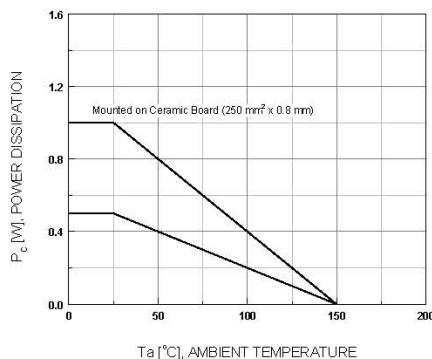
Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	120	V
Collector Emitter Voltage	V_{CEO}	120	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current	I_C	800	mA
Base Current	I_B	160	mA
Collector Power Dissipation	P_C	0.5 1) ¹⁾	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	- 55 to + 150	°C

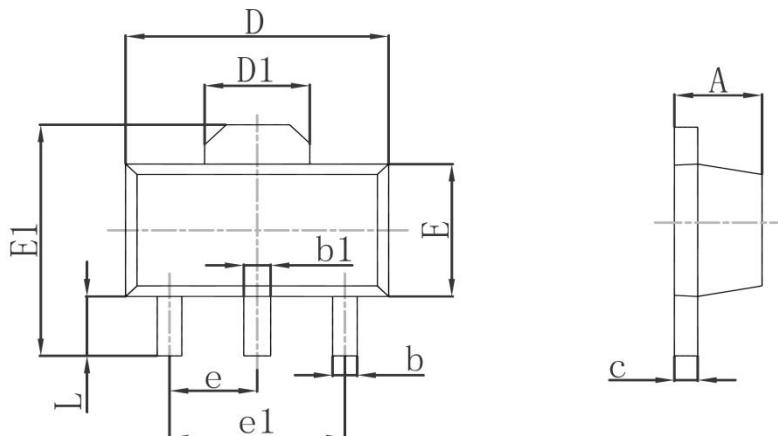
¹⁾ Mounted on ceramic board (250 mm² X 0.8 mm).**Characteristics at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 5 \text{ V}$, $I_C = 100 \text{ mA}$	h_{FE}	80	--	160	--
	h_{FE}	120		240	
Collector Base Cutoff Current at $V_{CB} = 120 \text{ V}$	I_{CBO}	-	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 5 \text{ V}$	I_{EBO}	-	-	100	nA
Collector Emitter Breakdown Voltage at $I_C = 1 \text{ mA}$	$V_{(BR)CEO}$	120	-	-	V
Emitter Base Breakdown Voltage at $I_E = 1 \text{ mA}$	$V_{(BR)EBO}$	5	-	-	V
Collector Emitter Saturation Voltage at $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$	$V_{CE(sat)}$	-	-	1	V
Base Emitter on Voltage at $V_{CE} = 5 \text{ V}$, $I_C = 500 \text{ mA}$	$V_{BE(on)}$	-	-	1	V
Transition Frequency at $V_{CE} = 5 \text{ V}$, $I_C = 100 \text{ mA}$	f_T	-	120	-	MHz
Collector Output Capacitance at $V_{CB} = 10 \text{ V}$, $f = 1 \text{ MHz}$	C_{ob}	-	-	30	pF

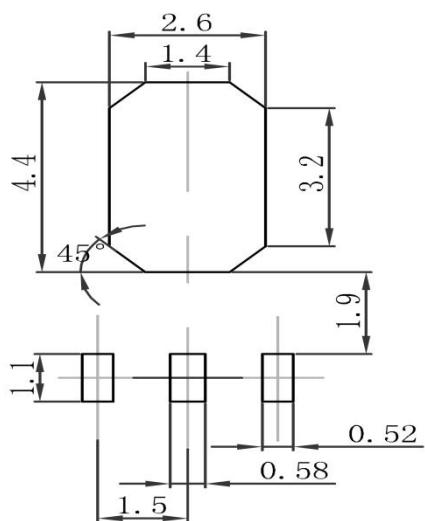
HSC2881U

Typical Characteristics

Figure 1. Static Characteristic**Figure 2. Base-Emitter On Voltage****Figure 3. DC Current Gain****Figure 4. Collector-Emitter Saturation Voltage****Figure 5. Power Derating**

HSC2881U**SOT-89 Package Outline Dimensions**

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550REF		0.061REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500TYP		0.060TYP	
e1	3.000TYP		0.118TYP	
L	0.900	1.200	0.035	0.047

SOT-89 Suggested Pad Layout**Note:**

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only